AMENDMENTS TO THE SPECIFICATION:

Please replace paragraph [0047] with the following amended paragraph:

[0047] The size of an auxiliary capacitance is determined by the area of overlapping between the auxiliary capacitor electrode 8 and the pixel electrode 10 and the material and thickness of the insulation film 9. To prevent deterioration of the display quality, such as display irregularity and crosstalk, it is preferable to set the auxiliary capacitance to a large value, but a thin insulation film 9 is liable to cause leakage defects. Thus it is necessary to select a suitable material for the insulation film 9 and suitably set its thickness in consideration of the insulation property and transmission property or permeability. In the first embodiment, an inorganic oxide such as SiO_2 or a resinous material such as acrylic resin is used to form the insulation film 9 in a thickness of about 0.1 μm. An ITO (indium-tin Oxide) film which is a transparent conductive film or the like is used to form the auxiliary capacitor electrode 8 and the pixel electrode 10. The auxiliary capacitor electrode 8 and the insulation film 9 have partially been removed in a predetermined pattern (see 12 in Fig. 1) at a through-hole 11. The pixel electrode 10 and a drain electrode 13 of the TFT 6 are connected to each other via the through-hole 11. Since the auxiliary capacitor electrode 8 in Figs. 1-2 is formed over the pixel region with the exception of the relatively small areas 12 and 14 outlined in dashed lines, the auxiliary capacitor electrode 8 overlaps a majority portion of the pixel electrode 10 and is provided over a majority portion of the display screen.